



PMBT3946YPN

40 V, 200 mA NPN/PNP general-purpose double transistor

23 November 2023

Product data sheet

1. General description

NPN/PNP general-purpose double transistor in a SOT363 (SC-88) very small Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: PMBT3904YS

PNP/PNP complement: PMBT3906YS

2. Features and benefits

- General-purpose double transistor
- Board-space reduction
- AEC-Q101 qualified

3. Applications

- General-purpose switching and amplification

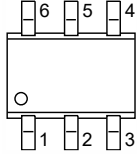
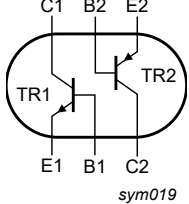
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Per transistor; for the PNP transistor with negative polarity						
V_{CEO}	collector-emitter voltage	open base	-	-	40	V
I_C	collector current		-	-	200	mA
TR1 (NPN)						
h_{FE}	DC current gain	$V_{CE} = 1 \text{ V}; I_C = 10 \text{ mA}; T_{amb} = 25 \text{ }^\circ\text{C}$	100	180	300	

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1	 <p>TSSOP6 (SOT363)</p>	 <p>sym019</p>
2	B1	base TR1		
3	C2	collector TR2		
4	E2	emitter TR2		
5	B2	base TR2		
6	C1	collector TR1		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PMBT3946YPN	TSSOP6	plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	SOT363

7. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
PMBT3946YPN	BB%

[1] % = placeholder for manufacturing site code

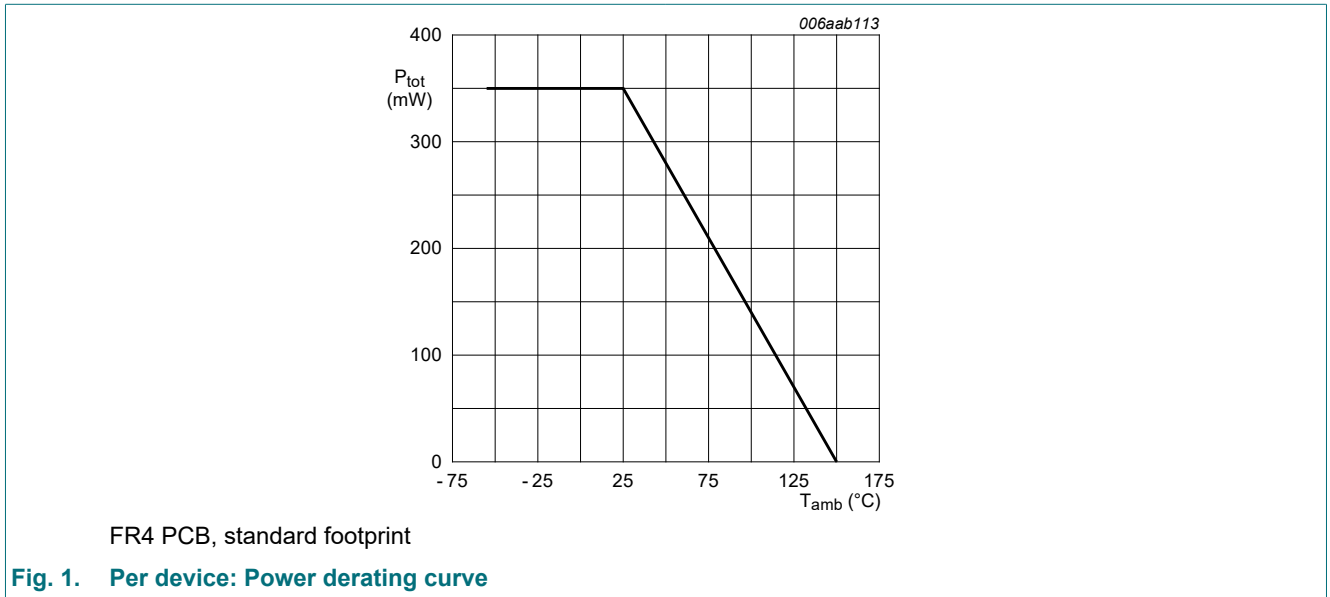
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
TR1 (NPN)					
V_{CBO}	collector-base voltage	open emitter	-	60	V
TR2 (PNP)					
V_{CBO}	collector-base voltage	open emitter	-	-40	V
Per transistor; for the PNP transistor with negative polarity					
V_{CEO}	collector-emitter voltage	open base	-	40	V
V_{EBO}	emitter-base voltage	open collector	-	6	V
I_C	collector current		-	200	mA
I_{BM}	peak base current	single pulse; $t_p \leq 1$ ms	-	100	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C	[1]	230	mW
Per device					
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C	[1]	350	mW
T_j	junction temperature		-	150	°C
T_{amb}	ambient temperature		-55	150	°C
T_{stg}	storage temperature		-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

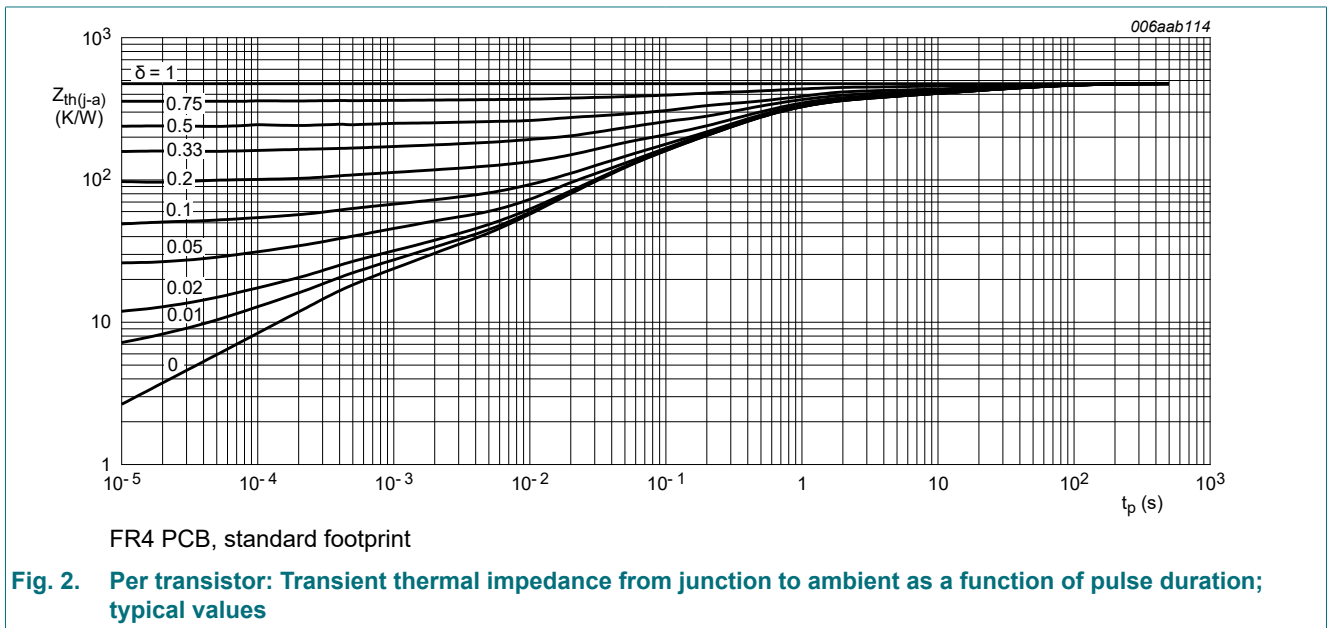


9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	543	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	290	K/W	
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient		[1]	-	-	357	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



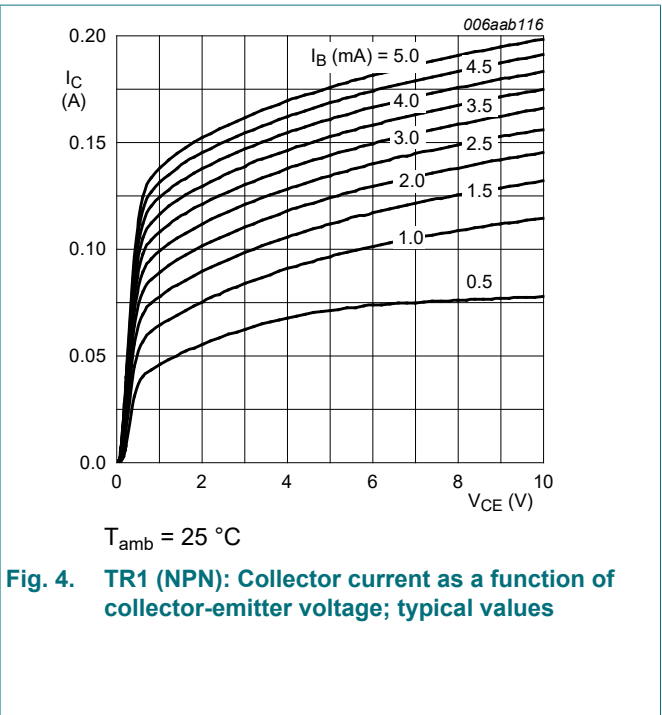
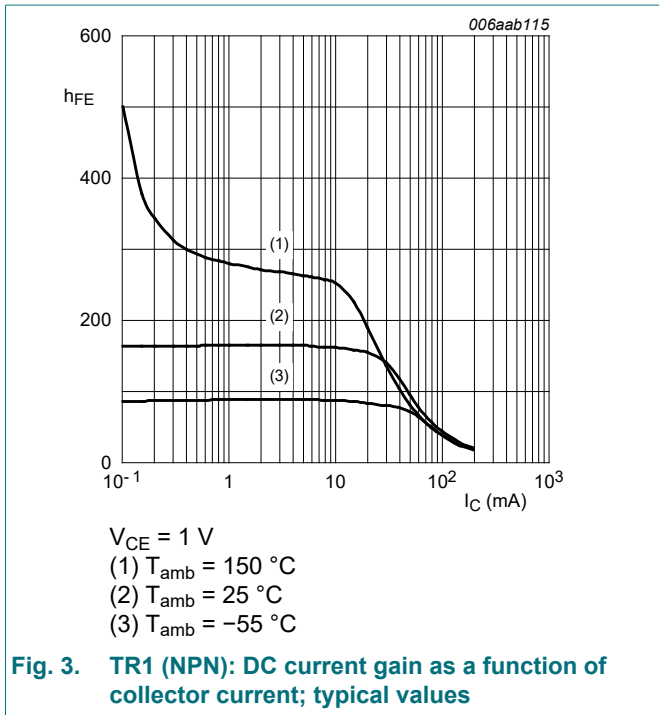
10. Characteristics

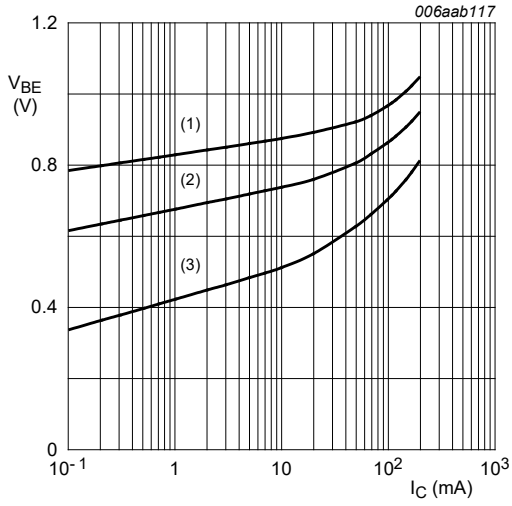
Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
TR1 (NPN)							
I_{CBO}	collector-base cut-off current	$V_{CB} = 30\text{ V}$; $I_E = 0\text{ A}$; $T_{amb} = 25\text{ °C}$	-	-	50	nA	
I_{EBO}	emitter-base cut-off current	$V_{EB} = 6\text{ V}$; $I_C = 0\text{ A}$; $T_{amb} = 25\text{ °C}$	-	-	50	nA	
h_{FE}	DC current gain	$V_{CE} = 1\text{ V}$; $I_C = 0.1\text{ mA}$; $T_{amb} = 25\text{ °C}$	60	180	-		
		$V_{CE} = 1\text{ V}$; $I_C = 1\text{ mA}$; $T_{amb} = 25\text{ °C}$	80	180	-		
		$V_{CE} = 1\text{ V}$; $I_C = 10\text{ mA}$; $T_{amb} = 25\text{ °C}$	100	180	300		
		$V_{CE} = 1\text{ V}$; $I_C = 50\text{ mA}$; $T_{amb} = 25\text{ °C}$	60	105	-		
		$V_{CE} = 1\text{ V}$; $I_C = 100\text{ mA}$; $T_{amb} = 25\text{ °C}$	30	50	-		
V_{CEsat}	collector-emitter saturation voltage	$I_C = 10\text{ mA}$; $I_B = 1\text{ mA}$; $T_{amb} = 25\text{ °C}$	-	75	200	mV	
		$I_C = 50\text{ mA}$; $I_B = 5\text{ mA}$; $T_{amb} = 25\text{ °C}$	-	120	300	mV	
V_{BEsat}	base-emitter saturation voltage	$I_C = 10\text{ mA}$; $I_B = 1\text{ mA}$; $T_{amb} = 25\text{ °C}$	650	750	850	mV	
		$I_C = 50\text{ mA}$; $I_B = 5\text{ mA}$; $T_{amb} = 25\text{ °C}$	-	850	950	mV	
t_d	delay time	$I_C = 10\text{ mA}$; $I_{Bon} = 1\text{ mA}$; $I_{Boff} = -1\text{ mA}$; $V_{CC} = 3\text{ V}$; $T_{amb} = 25\text{ °C}$	-	-	35	ns	
t_r	rise time		-	-	35	ns	
t_{on}	turn-on time		-	-	70	ns	
t_s	storage time		-	-	200	ns	
t_f	fall time		-	-	50	ns	
t_{off}	turn-off time		-	-	250	ns	
C_c	collector capacitance		$V_{CB} = 5\text{ V}$; $I_E = 0\text{ A}$; $i_e = 0\text{ A}$; $f = 1\text{ MHz}$; $T_{amb} = 25\text{ °C}$	-	-	4	pF
C_e	emitter capacitance		$V_{EB} = 0.5\text{ V}$; $I_C = 0\text{ A}$; $i_c = 0\text{ A}$; $f = 1\text{ MHz}$; $T_{amb} = 25\text{ °C}$	-	-	8	pF
f_T	transition frequency	$V_{CE} = 20\text{ V}$; $I_C = 10\text{ mA}$; $f = 100\text{ MHz}$; $T_{amb} = 25\text{ °C}$	300	-	-	MHz	
NF	noise figure	$V_{CE} = 5\text{ V}$; $I_C = 100\text{ }\mu\text{A}$; $R_S = 1\text{ k}\Omega$; $f = 10\text{ Hz to }15.7\text{ kHz}$	-	-	5	dB	
TR2 (PNP)							
I_{CBO}	collector-base cut-off current	$V_{CB} = -30\text{ V}$; $I_E = 0\text{ A}$; $T_{amb} = 25\text{ °C}$	-	-	-50	nA	
I_{EBO}	emitter-base cut-off current	$V_{EB} = -6\text{ V}$; $I_C = 0\text{ A}$; $T_{amb} = 25\text{ °C}$	-	-	-50	nA	
h_{FE}	DC current gain	$V_{CE} = -1\text{ V}$; $I_C = -0.1\text{ mA}$; $T_{amb} = 25\text{ °C}$	60	180	-		
		$V_{CE} = -1\text{ V}$; $I_C = -1\text{ mA}$; $T_{amb} = 25\text{ °C}$	80	180	-		
		$V_{CE} = -1\text{ V}$; $I_C = -10\text{ mA}$; $T_{amb} = 25\text{ °C}$	100	180	300		
		$V_{CE} = -1\text{ V}$; $I_C = -50\text{ mA}$; $T_{amb} = 25\text{ °C}$	60	130	-		
		$V_{CE} = -1\text{ V}$; $I_C = -100\text{ mA}$; $T_{amb} = 25\text{ °C}$	30	50	-		
V_{CEsat}	collector-emitter saturation voltage	$I_C = -10\text{ mA}$; $I_B = -1\text{ mA}$; $T_{amb} = 25\text{ °C}$	-	-100	-250	V	
		$I_C = -50\text{ mA}$; $I_B = -5\text{ mA}$; $T_{amb} = 25\text{ °C}$	-	-165	-400	V	
V_{BEsat}	base-emitter saturation voltage	$I_C = -10\text{ mA}$; $I_B = -1\text{ mA}$; $T_{amb} = 25\text{ °C}$	-	-750	-850	mV	
		$I_C = -50\text{ mA}$; $I_B = -5\text{ mA}$; $T_{amb} = 25\text{ °C}$	-	-850	-950	mV	

40 V, 200 mA NPN/PNP general-purpose double transistor

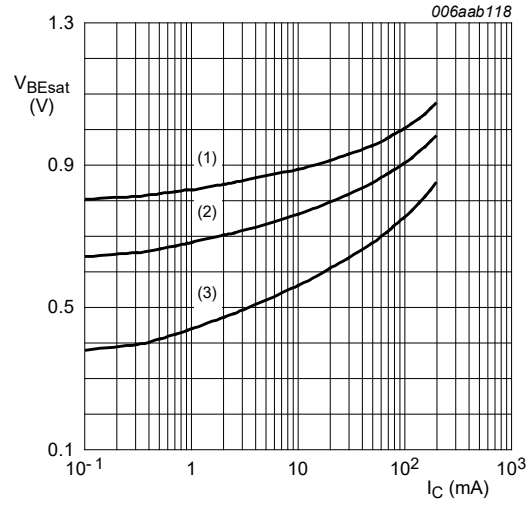
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t_d	delay time	$I_C = -10 \text{ mA}; I_{B\text{on}} = -1 \text{ mA}; I_{B\text{off}} = 1 \text{ mA};$ $V_{CC} = -3 \text{ V}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	35	ns
t_r	rise time		-	-	35	ns
t_{on}	turn-on time		-	-	70	ns
t_s	storage time		-	-	225	ns
t_f	fall time		-	-	75	ns
t_{off}	turn-off time		-	-	300	ns
C_c	collector capacitance	$V_{CB} = -5 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz};$ $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	4.5	pF
C_e	emitter capacitance	$V_{EB} = -0.5 \text{ V}; I_C = 0 \text{ A}; i_c = 0 \text{ A};$ $f = 1 \text{ MHz}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	10	pF
f_T	transition frequency	$V_{CE} = -20 \text{ V}; I_C = -10 \text{ mA}; f = 100 \text{ MHz};$ $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	250	-	-	MHz
NF	noise figure	$V_{CE} = -5 \text{ V}; R_S = 1 \text{ k}\Omega; I_C = -100 \text{ }\mu\text{A}; f =$ $10 \text{ Hz to } 15.7 \text{ kHz}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	4	dB





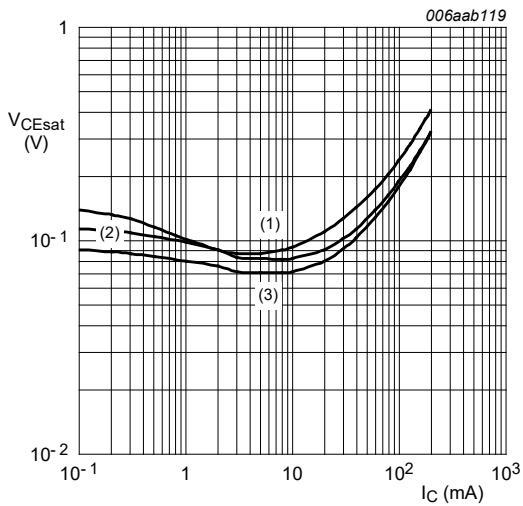
$V_{CE} = 1\text{ V}$
 (1) $T_{amb} = -55\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = 150\text{ °C}$

Fig. 5. TR1 (NPN): Base-emitter voltage as a function of collector current; typical values



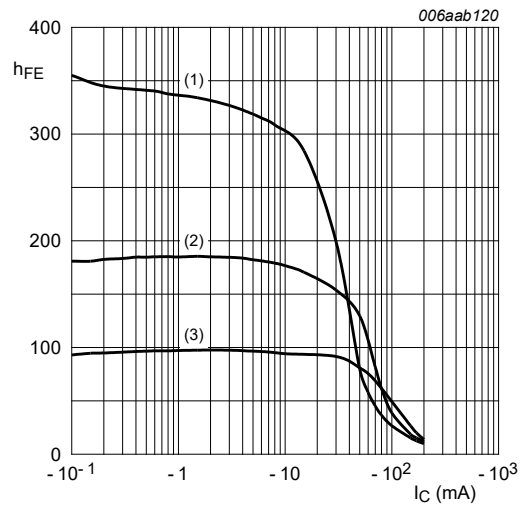
$I_C/I_B = 10$
 (1) $T_{amb} = -55\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = 150\text{ °C}$

Fig. 6. TR1 (NPN): Base-emitter saturation voltage as a function of collector current; typical values



$I_C/I_B = 10$
 (1) $T_{amb} = 150\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -55\text{ °C}$

Fig. 7. TR1 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values



$V_{CE} = -1\text{ V}$
 (1) $T_{amb} = 150\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -55\text{ °C}$

Fig. 8. TR2 (PNP): DC current gain as a function of collector current; typical values

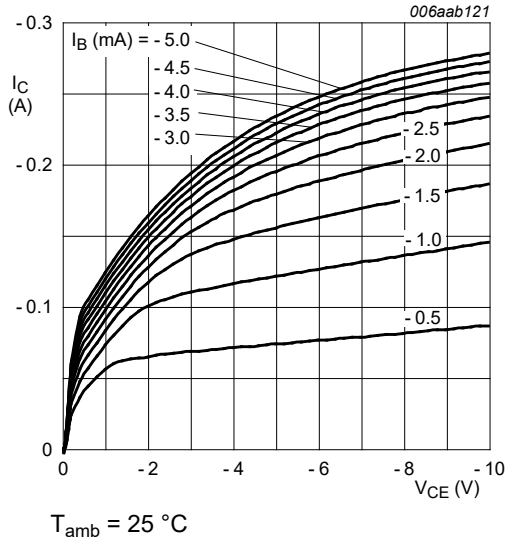


Fig. 9. TR2 (PNP): Collector current as a function of collector-emitter voltage; typical values

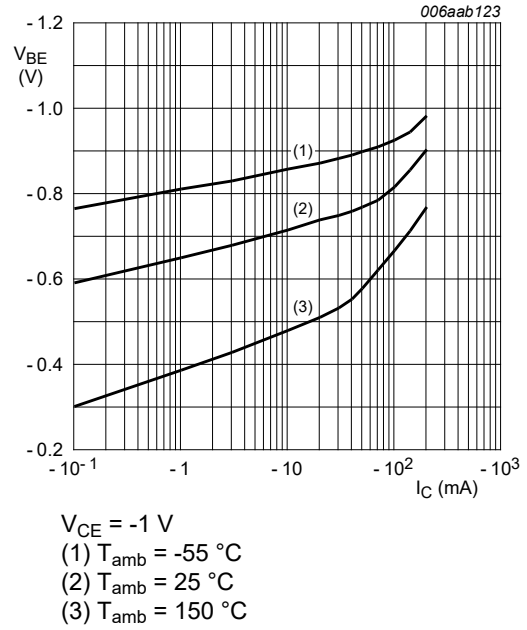


Fig. 10. TR2 (PNP): Base-emitter voltage as a function of collector current; typical values

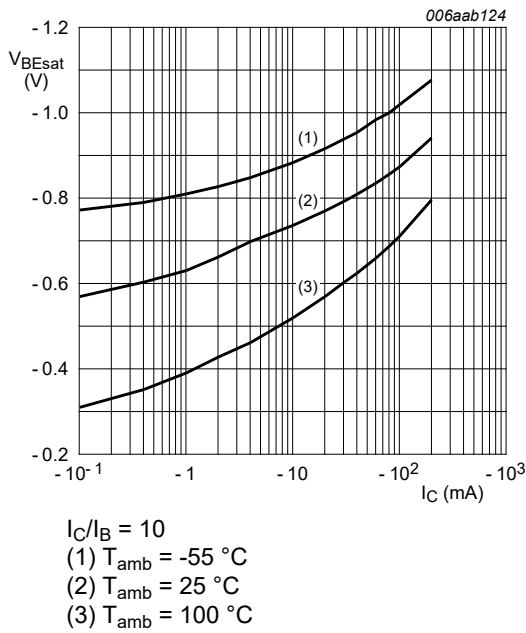


Fig. 11. TR2 (PNP): Base-emitter saturation voltage as a function of collector current; typical values

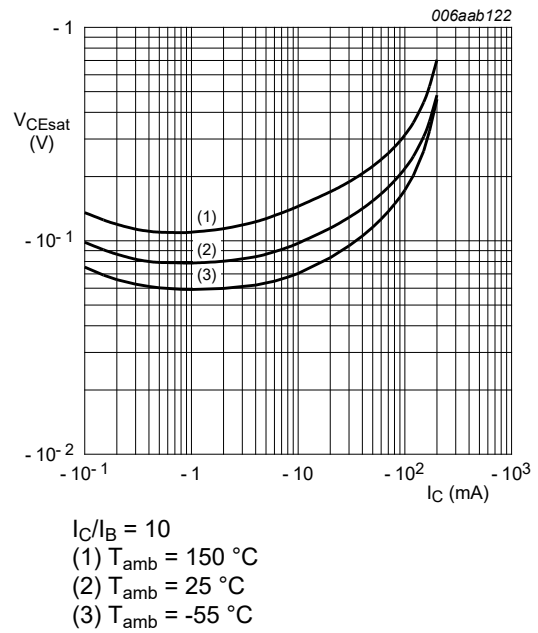


Fig. 12. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values

11. Test information

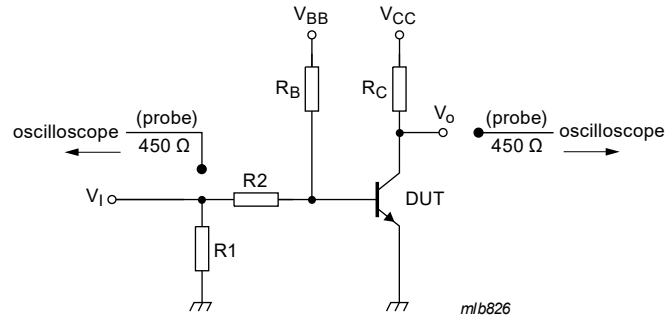


Fig. 13. TR1 (NPN): Test circuit for switching times

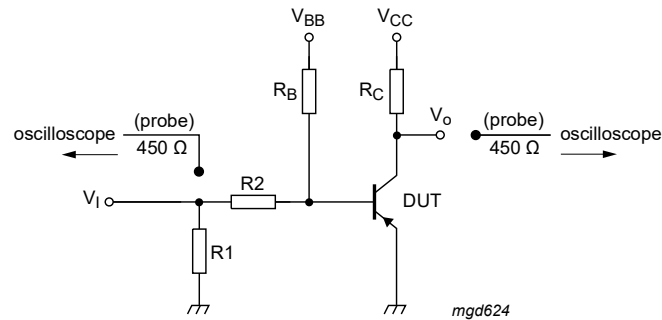


Fig. 14. TR2 (PNP): Test circuit for switching times

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline

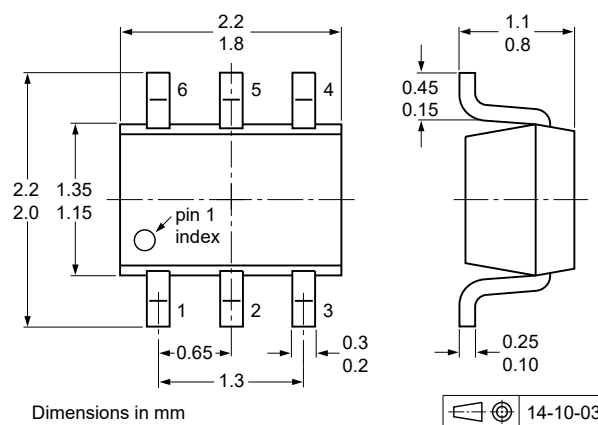


Fig. 15. Package outline TSSOP6 (SOT363)

13. Soldering

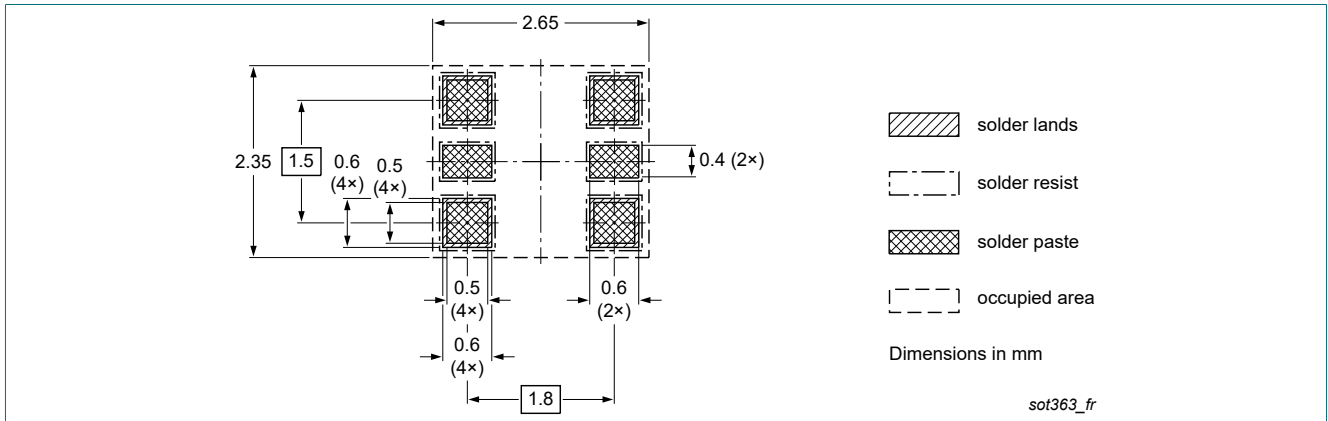


Fig. 16. Reflow soldering footprint for TSSOP6 (SOT363)

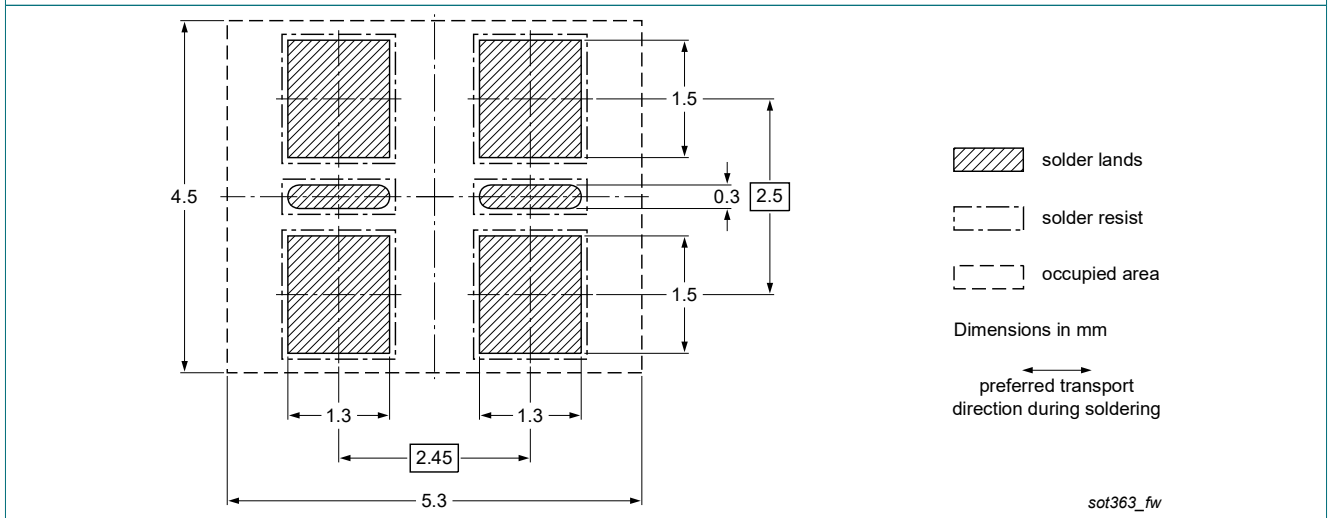


Fig. 17. Wave soldering footprint for TSSOP6 (SOT363)

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMBT3946YPN v.2	20231123	Product data sheet	-	PMBT3946YPN v.1
Modifications:	<ul style="list-style-type: none">The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.Legal texts have been adapted to the new company name where appropriate.			
PMBT3946YPN v.1	20090512	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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